

Correction to “Identification of Killer Defects in Kesterite Thin-Film Solar Cells”

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ACS Energy Lett. 2018, 3 (2), pp 496–500. DOI: 10.1021/acsenerylett.7b01313

An error was found in the labeling of Figure 4, which does not affect the results or analysis contained in the Letter. The label for the lowest potential energy curve (blue line) of $V_S^{1+} + e^-$ in Figure 4b should appear as V_S^{1+} . The complete cycle for recombination is therefore

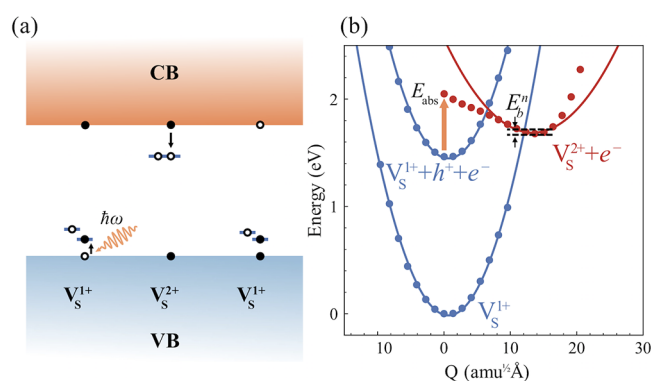
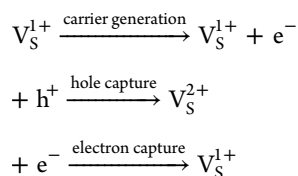


Figure 4. (a) Proposed nonradiative recombination process where a V_S defect is photoactivated into a V_S^{2+} state that facilitates electron capture. (b) Configuration coordinate diagram for the same process; the dots represent calculated points on the potential energy surface, while lines are a parabolic fit. The labels E_{abs}^n and E_b^n represent the optical excitation and electron capture barrier, respectively.

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Published: April 5, 2018